



#### 6600W SURFACE MOUNT TRANSIENT VOLTAGE SUPPRESSOR

### Product Summary (@TA = +25°C)

P <sub>PK</sub>	I <sub>FSM</sub> (A)	V <sub>RWM</sub> (V)	PM <sub>(AV)</sub>
6600W	700	10 to 43	W8

### **Features and Benefits**

- 6600W Peak Pulse Power Dissipation
- T<sub>J</sub> = +175°C Capability Suitable for High Reliability and Automotive Requirement
- High Current Capability
- Excellent High-Temperature Stability
- Meets ISO7637-2 Surge Capability
- Meets ISO16750-2 Surge Specification
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DM8W10AQ-DM8W43AQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

### **Description and Applications**

The DM8W10AQ-DM8W43AQ are suitable to protect sensitive automotive circuits against surges defined in ISO7637-2 and against load-dump surge according to ISO16750-2.

The devices meet compliance with the following standards:

- ISO 16750-2, Pulse A and Pulse B
- ISO 7637-2 (Note 5)
   Pulse 1, Pulse 2a, Pulse 3a, Pulse 3b

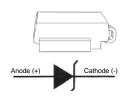
#### **Mechanical Data**

- Package: DO-218
- Package Material: Molded Plastic.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead-Free Plating (Matte Tin Finish).
   Solderable per MIL-STD-202, Method 208 (3)
- Polarity Indicator: Heatsink is Anode
- Weight: 2.74 grams (Approximate)

DO-218 (Type E)



Top View



Polarity: Heatsink is Anode

Pin Information

### **Ordering Information (Note 4)**

Part Number	Qualification	Paakaga	Packing		
Fait Number	Qualification	Package	Qty.	Carrier	
DM8WxxAQ-13	Automotive	DO-218 (Type E)	750	Tape & Reel	

\*x = Device Voltage, e.g., DM8W18AQ-13

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/
- 5. Not applicable to parts with stand-off voltage lower than the average battery voltage (13.5V).



### **Marking Information**



M8WxxA = Product Type Marking Code (i.e. M8W18A for DM8W18AQ-13) 11 = Manufacturers' Code Marking

aa: Wafer source code

y: Year (M = 2022)

m: Month (1 - C)d: Date (1 – V)

cc: Lot serial number

Bar Denotes Cathode Pin, Circle Denotes Anode

Date Code Key

Year	2018	 2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	- 1	 М	N	0	Р	Q	R	S	Т	U	V

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	Α	В	С
Date	1	2	3		9	10	11	12		29	30	31
Code	1	2	3		9	Α	В	С		Т	U	V

# 

Characteristic	Symbol	Value	Unit	
Peak Pulse Power Dissipation	10/1000µs Waveform		6600	
(Non Repetitive Current Pulse Derated above $T_A = +25^{\circ}C$ ) (Note 6)	10/10000µs Waveform	$P_PK$	5200	W
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load (	I <sub>FSM</sub>	700	А	
Steady State Power Dissipation @ Tc = +25°C	PM <sub>(AV)</sub>	8.0	W	

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case	R <sub>eJC</sub>	0.9	°C/W
Operating Temperature Range	TJ	-55 to +175	°C
Storage Temperature Range	Tstg	-55 to +175	°C

Notes:

<sup>6.</sup> Valid provided that terminals are kept at ambient temperature.

<sup>7.</sup> Measured on 8.3ms single half sine-wave or equivalent square wave. Duty cycle = 4 pulses per minute maximum.



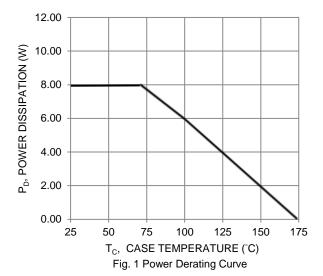
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Part Number	Reverse Standoff Voltage	Vol	kdown tage r (Note 8)	Test Current	Max. Reverse Leakage @ V <sub>RWM</sub> (Note 10)	Max. Clamping Voltage @ I <sub>pp</sub>	Max. Peak Pulse Current I <sub>pp</sub> at 10/1000µs (Note 9)	Maximum Leakage at Vwm T <sub>J</sub> = +175°C
	V <sub>RWM</sub> (V)	Min (V)	Max (V)	Iτ (mA)	IR (μA)	Vc (V)	(A)	I <sub>D</sub> (μ <b>A</b> )
DM8W10AQ	10	11.1	12.3	5	15	17.0	388	250
DM8W11AQ	11	12.2	13.5	5	10	18.2	363	150
DM8W12AQ	12	13.3	14.7	5	10	19.9	332	150
DM8W13AQ	13	14.4	15.9	5	10	21.5	307	150
DM8W14AQ	14	15.6	17.2	5	10	23.2	284	150
DM8W15AQ	15	16.7	18.5	5	10	24.4	270	150
DM8W16AQ	16	17.8	19.7	5	10	26.0	254	150
DM8W17AQ	17	18.9	20.9	5	10	27.6	239	150
DM8W18AQ	18	20.0	22.1	5	10	29.2	226	150
DM8W20AQ	20	22.2	24.5	5	10	32.4	204	150
DM8W22AQ	22	24.4	26.9	5	10	35.5	186	150
DM8W24AQ	24	26.7	29.5	5	10	38.9	170	150
DM8W26AQ	26	28.9	31.9	5	10	42.1	157	150
DM8W28AQ	28	31.1	34.4	5	10	45.4	145	150
DM8W30AQ	30	33.3	36.8	5	10	48.4	136	150
DM8W33AQ	33	36.7	40.6	5	10	53.3	124	150
DM8W36AQ	36	40.0	44.2	5	10	58.1	114	150
DM8W40AQ	40	44.4	49.1	5	10	64.5	102	150
DM8W43AQ	43	47.8	52.8	5	10	69.4	95.1	150

Notes:

- 8. V<sub>BR</sub> measured with I<sub>T</sub> current pulse = 10ms to 15ms.
  9. Per 10 × 1000µs waveform. See Figure 3.
  10. Short duration pulse test used so as to minimize the self-heating effect.





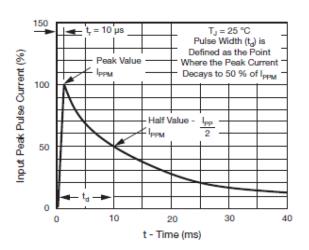


Fig. 3 - Pulse Waveform

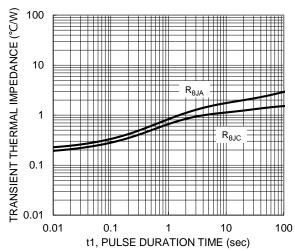


Fig. 5 Typical Transient Thermal Impedance

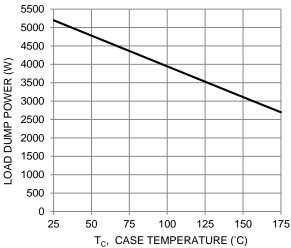


Fig. 2 Load Dump Power Characteristics (10ms Exponential Waveform)

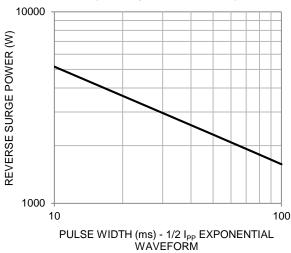


Fig. 4 Reverse Power Capability

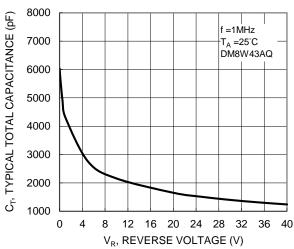


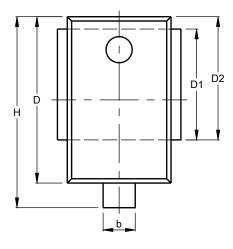
Fig. 6 Typical Total Capacitance (DM8W43AQ Only)

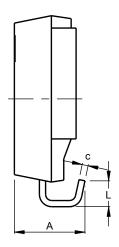


# **Package Outline Dimensions**

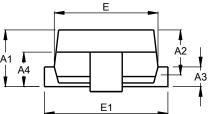
Please see http://www.diodes.com/package-outlines.html for the latest version.

### DO-218 (Type E)





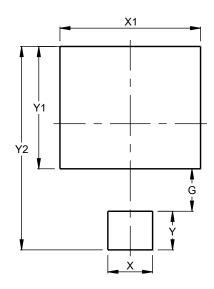
DO-218								
(Type E)								
Dim	Min	Max	Тур					
Α	4.70	5.70						
A1	4.70	5.25	5.00					
A2	3.45	4.26	3.95					
A3	1.70	2.50	2.00					
A4	2.58	3.55	3.10					
b	2.30	3.00						
C	0.45	0.90						
D	13.20	13.80	13.50					
D1	8.70	9.30	9.00					
D2	9.70	10.30	10.00					
Е	8.20	8.80	8.50					
E1	9.50	10.50						
Н	15.00	16.00	15.50					
L	1.50	2.50	2.00					
All								



# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### DO-218 (Type E)



Dimensions	Value (in mm)
G	3.30
Х	3.50
X1	11.00
Υ	3.00
Y1	9.50
Y2	15.80



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